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an electron-emitting device, comprising a semiconductor formed between opposing electrodes and wherein fine particles are dispersed within said semiconductor layer or on said semiconductor layer, and

a phosphor, wherein said phosphor emits light by a stimulation of the electrons emitted from said electron-emitting device.--

REMARKS

The claims are 67-154.

The title has been amended to more accurately describe Applicants' invention.

The first page has been amended after the title to recite, "This is a continuation-in-part of application Serial No. 07/218,203 filed July 13, 1988."

New drawings Figs. 39A - 39C showing a display device have been added.

The specification has been amended to correct minor errors in spelling and syntax and to correct collating errors. Specification page 89 is a duplicate of page 88.

Original pages 93 and 94 were numbered inversely and correction is required.

The following additions have been made to the specification:

 Page 8, after line 8, a brief description of added drawings Figs. 39A, 39B and 39C;

- 2. Page 55, after line 4, a detailed description of the display device with reference to the drawings; and
- 3. Page 85, after line 4, Example 29 was added illustrating the operation of display devices of Figs. 39A 39C.

It is respectfully requested that the claims be allowed and the application passed to issue.

INFORMATION DISCLOSURE STATEMENT

Pursuant to 37 C.F.R. § 1.56, the Examiner's attention is drawn to the documents listed on the enclosed Form PTO-1449. Copies of the listed documents were provided in parent application Serial No. 07/218,203.

U.S. Patents:

	Patent No.	<u> Issue Date</u>	Inventors
1.	4,093,562	6/6/78	Kishimoto
2.	4,325,084	4/13/82	Van Gorkom et al.
3.	3,278,789	10/11/66	Shroff
4.	3,735,186	5/22/73	Klopfer et al.

Foreign Patent Document:

Document No. Date	of Publication	Country
2,060,991	5/7/81	United Kingdom
SU-A-855,782	8/15/81	Soviet Union
DE-B2-2,413,942	2/15/79	Germany
(U.S. Equivalent		_
3,998,678)		
DE-B-1,800,952	7/22/71	Germany
DE-B1-2,542,349	7/10/76	Germany
DE-B2-2,012,101	3/6/75	Germany
(U.S. Equivalent		_
3,678,325		
	2,060,991 SU-A-855,782 DE-B2-2,413,942 (U.S. Equivalent 3,998,678) DE-B-1,800,952 DE-B1-2,542,349 DE-B2-2,012,101 (U.S. Equivalent	2,060,991 5/7/81 SU-A-855,782 8/15/81 DE-B2-2,413,942 2/15/79 (U.S. Equivalent 3,998,678) DE-B-1,800,952 7/22/71 DE-B1-2,542,349 7/10/76 DE-B2-2,012,101 3/6/75 (U.S. Equivalent

11.	DE-A-1,764,994	1/13/72	Germany
	(U.S. Equivalent		
	3,466,485)		
12.	EP-A2-0073031	3/2/83	European
13.	GB-A-1,267,029	3/5/72	Great Britain
14.	GB-A-1,335,979	10/31/73	Great Britain
15.	Kokai-56-18336	2/4/81	Japan
	(Abstract Only)		
16.	Kokai-56-71239	6/13/81	Japan
	(Abstract Only)	•	

Articles:

- 17. M. Hartwell et al., "Strong Electron Emission From Patterned Tin-indium Oxide Thin Films", Cambridge, MA, pp. 519-521
- 18. M. Elinson et al., "The Emission Of Hot Electrons And The Field Emission Of Electrons From Tin Oxide", Radio Engineering and Electronic Physics, No. 7, July 1965, pp. 1290-1296

Each of the references was made of record in the parent application Serial No. 07/218,203 and may be deemed pertinent for the reasons recited therein.

It is respectfully requested that the above be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be returned indicating that they have been considered.

Applicants' undersigned attorney may be reached by telephone in our New York Office at

(212) 758-2400.

All correspondence should continue to be directed to our below listed address.

Respectfully submitted,

Attorney for Applicants

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